

FMAM5082 DATA SHEET

1000 to 2500 MHz SMA GaN Power Amplifier with Integrated Heatsink and Cooling Fan, 18W, L & S Band, 28V, 50% Efficiency and Class AB

The FMAM5082 is a Class AB high power amplifier with an integrated Heatsink/ Cooling Fan assembly that operates in L and S bands from 1000 MHz to 2500 MHz and generates 18 Watts of CW RF power and 2.5 Watts of linear power with 5% EVM @ 34 dBm. The module utilizes the latest Gallium Nitride (GaN) semiconductor technology with 30% to 50% power added efficiency. The amplifier package design features a small form factor of 3.9in³ that's ideal for size, weight, and power (SWaP) constrained applications used in broadband RF telemetry, tactical communication, electronic warfare, and unmanned aircraft systems, as well as software defined radios. Impressive typical performance includes 47 dB of linear gain, 1.8:1 VSWR, +42 dBm third order intercept point, and harmonic suppression of -11 dBc. Additionally with a nominal 0 dBm (1 mW) RF input power, the amplifier can provide 40 dB of gain. Operating voltage is +28 Vdc with 1.9A of DC current. Additional features include overvoltage protection, reverse voltage protection, and logic on/off control. The rugged Mil-Grade assembly supports female SMA RF input/output connectors and a micro-D 9 pin socket command control connector with an accessory cable assembly included. The integrated heatsink with cooling fan operates at +28Vdc and includes an accessory cable with banana plugs. The operating baseplate temperature range is -40°C to +85°C and the unit is guaranteed to withstand up to 95% relative humidity, altitude levels up to 30,000 ft, and random vibration and shock profiles (see chart below). Pasternak also offers an accessory Harmonic filter option, model FMHFL0000 that can be used at the output of the power amplifier. This lowpass RF filter has low insertion loss with power handling up to 50W and specifically designed to reduce harmonics at the output of transmitters operating at up through L & S Bands and offers rejection levels of greater than 25 dB from 3.25 GHz to 5 GHz. The filter is offered in a miniature SMA connectorized package.

Electrical Specifications

(TA = +25°C, DC Voltage = 28Volts, DC Current = 1.9A)

Description	Min	Тур	Max	Unit
Frequency Range	1		2.5	GHz
Small Signal Gain		47		dB
Gain Flatness		±3		dB
Input Power (CW)		+0		dBm
Psat	10	18	23	Watts
Efficiency (PAE)	27	35		%
P1dB		+38		dBm
Output 3rd Order Intercept Point		+42		dBm
Output Mismatch			10:1	
2nd Harmonics		-21	-8	dBc
3rd Harmonics		-24	-11	dBc
Impedance (Input)		50		Ohms
Impedance (Output)		50		Ohms
Input VSWR		1.8:1	3.5:1	
Switching Speed for On/Off Switch Gate			2	usec
Operating DC Voltage	11	28	32	Volts
Operating DC Current	1.5	1.9	2.1	Α
Quiescent Current Bias		350		mA
Operating Temperature Range	-40		+85	°C



Features:

- 18W GaN High Power Amplifier
- Integrated Heatsink/ Cooling Fan Assembly
- L & S Band Class AB Design
- Frequency Range: 1000 MHz to 2500 MHz
- 47 dB linear Gain
- VSWR: 1.8:1
- +42 dBm IP3
- 2.5W Linear Power with 5% EVM @ 43 dBm
- PAE: 30% to 50%
- Small Form Factor Rugged Mil-Grade Package
- 50 Ohm Design
- Female SMA RF Connectors
- +28Vdc @1.9A DC current
- -40°C to +85°C Operating Baseplate Temperature
- Output Harmonic Filter Accessory Option

Applications:

- · Broadband RF Telemetry
- RF Communications Systems
- Electronic Warfare Airborne Electronic Attack
- Unmanned Aircraft Systems (UAS)
- Unmanned Ground Vehicles (UGV), Software Defined Radios
- Data Links
- Transmitters
- Test & Measurement
- · Telecom Infrastructure

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Performance	by Fr	equen	су
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Description	F1	F2	F3	F4	Units
Frequency Condition	1.0	1.5	2.0	2.5	GHz
Output Power @ 1dB Compresssion, Typ	31	31	36	38	dBm
Small Signal Gain, Typ (@-30dBm input)	50	49	47	46	dB
Third Order Intercept Point	42	42	39	41	dBm

Absolute Maximum Rating

Parameter	Rating	Unit
Max Device Voltage	32	V
Max Device Current	2.4	А
Max RF Input Power, $Z_L = 50 \Omega$	10	dBm
Max Operating Temperature (ambient)	60	°C
Max Operating Temperature (baseplate)	85	°C
Max Storage Temperature	85	°C



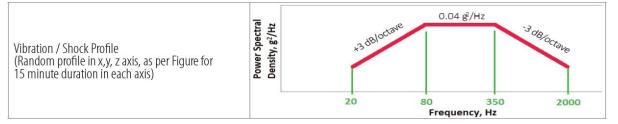
ESD Sensitive Material, Transport material in Approved ESD bags. Handle only in approved ESD Workstation.

Mechanical Specifications

Size

Length 3 in [76.2 mm]
Width 2 in [50.8 mm]
Height 0.65 in [16.51 mm]
Weight 1.4 lbs [635.03 g]
Input Connector SMA Female
Output Connector SMA Female
Bias Connector 9-Pin Micro-D Socket

Environmental Specifications



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Temperature

Operating Range -40 to +85 deg CStorage Range -55 to +85 deg C

Humidity 95% Non-Condensing
Altitude MIL-STD-810F Method 5004

Compliance Certifications (see product page for current document)

Plotted and Other Data

Notes:

• Values at 25 °C, sea level



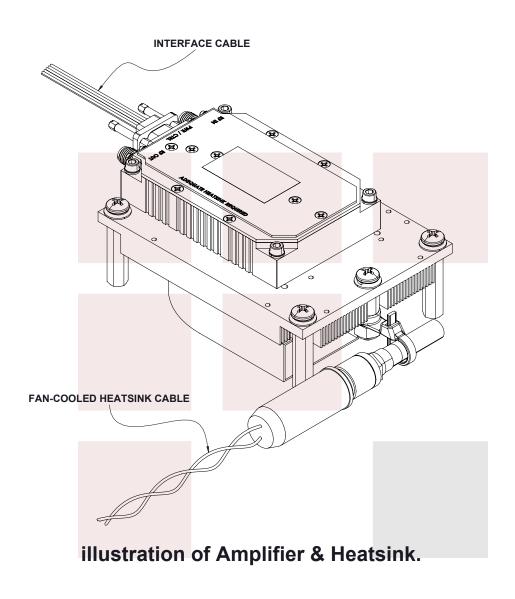


Amplifier Power-up Precautions

- 1.) Confirm that proper ESD precautions and controls are always in place before handling any Amplifier module.
- 2.) Confirm adequate thermal management is in place to effectively dissipate heat away from the Amplifier package. The Amplifier operational baseplate temperature must be within the operational temperature range stated in the Amplifier datasheet. Depending on the design and thermal requirements, using a heatsink with cooling fan is always recommended for safe reliable operation. A heat sink without a cooling fan may also be used. Damage caused from overheating will void the warranty.
- 3.) Confirm adequate system grounding is established. The DC power supply and Amplifier must have a common ground in order to operate properly.
- 4.) Power Amplifiers may require additional DC Current when initially powered-up. Depending on the design, the input current draw could range from an additional 10% to 100% above the maximum rated DC current of the Amplifier. This varies based on product part number.
- 5.) Confirm the DC power supply, if limited, is set to allow for additional start-up current that's rated for the Power Amplifier.
- 6.) Confirm the system is designed and calibrated for 50 ohms. Any impedance mismatch may cause performance issues.
- 7.) Perform a CALIBRATION (if required) with the loads before connecting the Amplifier to the Network Analyzer to ensure proper performance.
- 8.) Use a fixed attenuator between the signal source and input port of the Amplifier to optimize the input VSWR match.
- 9.) Confirm the input power level at the input port of the amplifier does not exceed the maximum rated limit for input power (as stated in the Amplifier datasheet).
 - P_{in} for Small Signal Gain = P1dB-SSG-10 dB
 - Pin for P1dB = P1dB-SSG+1 dB
- 10.) Confirm the Network Analyzer is always connected to the Amplifier first before DC power is applied to the Amplifier.
- 11.) As long as the input and output ports of the amplifier are connected to a 500hm load and RF signal power is applied, the Amplifier can be powered up with DC voltage.
- 12.) Confirm the Amplifier output load is matched for a 50 Ohm impedance and will not exceed the maximum rated VSWR or Return Loss limit for the Amplifier. Exceeding the maximum rated VSWR or Return Loss limit will result in reflected signal power that could damage the Amplifier and void the warranty.
- 13.) Power Amplifier connected to an Antenna for signal transmission It's strongly recommended to use a high power fixed attenuator pad or an Isolator between the output port of the Amplifier and input port to the antenna. Any reflected signal power due to impedance mismatch will likely damage the Amplifier and void the warranty.
- 14.) The attenuator or isolator used at the output port of the Amplifier must be rated to handle the output power level and operational frequency band of the amplifier.





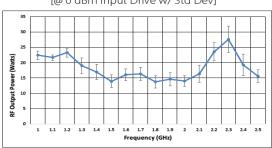


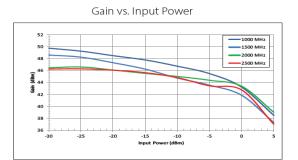




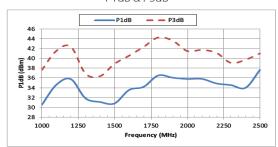
Typical Performance Data

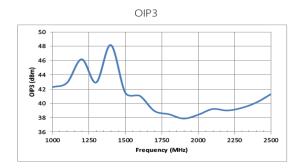
RF Output Power vs. Frequency
[@ 0 dBm Input Drive w/ Std Dev]



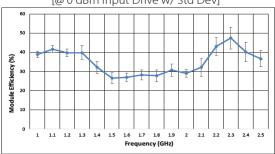


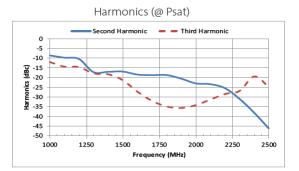
P1dB & P3dB



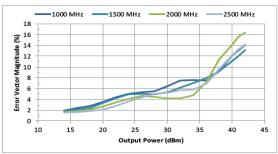


Frequency vs. Module Efficiency [@ 0 dBm Input Drive w/ Std Dev]

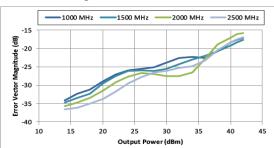




Error Vector Magnitude (%) [w/ OFDM Waveform]

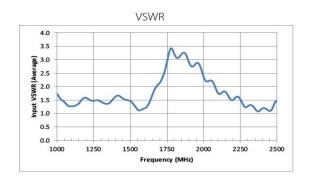


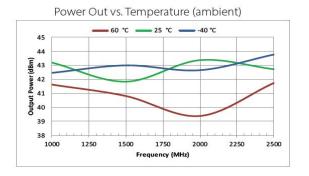
Error Vector Magnitude (dB) [w/ OFDM Waveform]



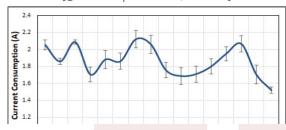








Current Consumption vs. Frequency
[@ 0 dBm Input Drive w/ Std Dev]



1000 to 2500 MHz SMA GaN Power Amplifier with Integrated Heatsink and Cooling Fan, 18W, L & S Band, 28V, 50% Efficiency and Class AB from Fairview Microwave is in-stock and available to ship same-day. All of our RF/microwave products are available off-the-shelf from our ISO 9001:2008 certified facilities in Lewisville, Texas. Fairview Microwave is RF on-demand.

For additional information on this product, please click the following link: 1000 to 2500 MHz SMA GaN Power Amplifier with Integrated Heatsink and Cooling Fan, 18W, L & S Band, 28V, 50% Efficiency and Class AB FMAM5082

URL: https://www.fairviewmicrowave.com/47db-high-power-high-gain-amplifier-18dbm-fmam5082-p.aspx

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